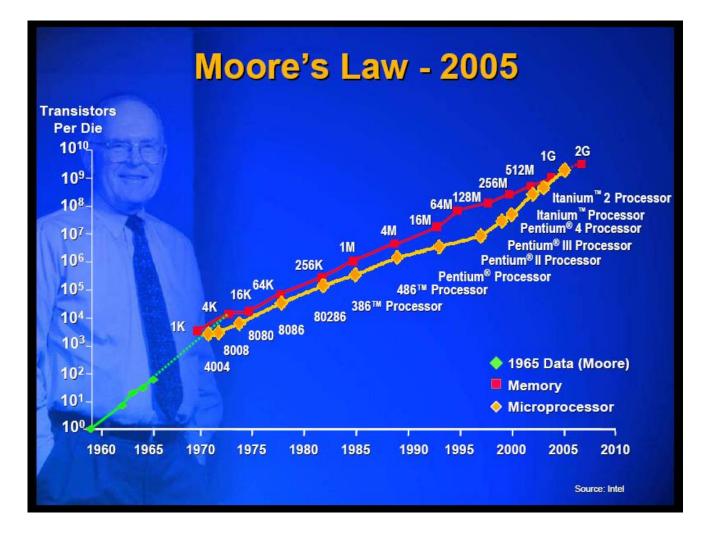
Nanoimprint Lithography

Anthony J. Lucio
Shaw Group Meeting
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- The number of transistors on integrated circuits doubles approximately every two years
- When will it end?
 - Some sources say we are at the "inflection point" for this trend!

Requirements of Lithography

Critical Dimension (CD) control:

 Sizes must be controlled within wafer and from wafer-towafer during fabrication

Overlay:

For high yield, alignment must be precisely controlled

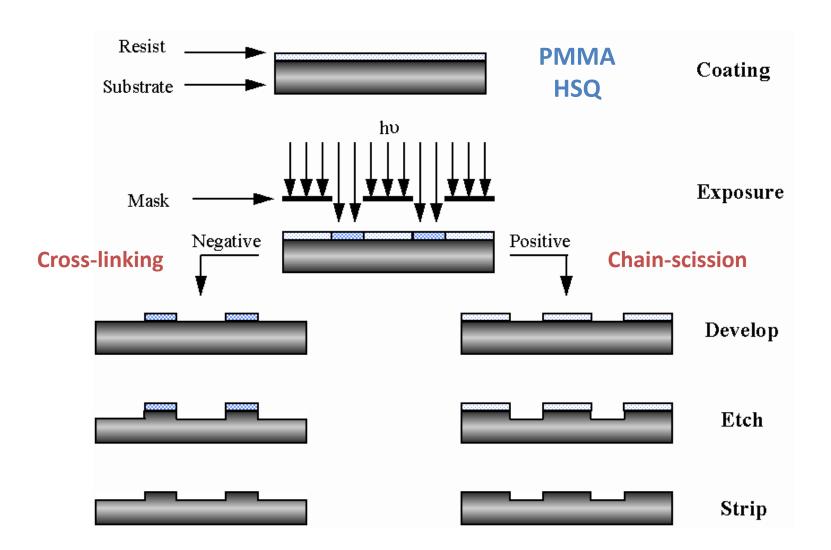
Defect Control:

 Other than designed pattern, no additional patterns must be imaged; avoid proximity effects

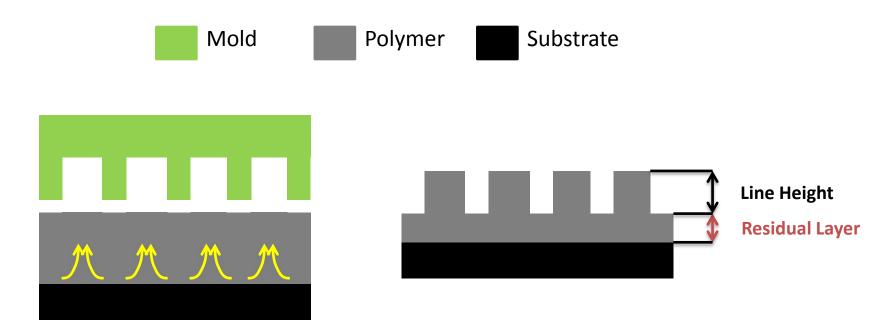
Low Cost:

Tool, resist, mask; fast step-and-repeat

Conventional Photolithography

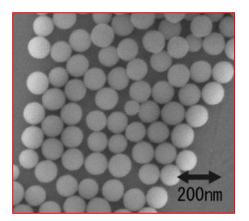


Nanoimprint Lithography (NIL)



- Thermal NIL is a **three-dimensional** patterning technique with numerous application in nanotechnology
- No need for expensive/complex optics or high-energy radiation sources
- However, relies on other lithographic techniques for template fabrication
- Control over <u>adhesion</u> between mold and polymer resist <u>is important!</u>

Interesting Research

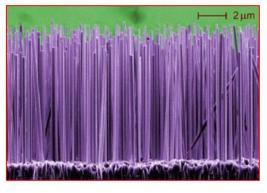




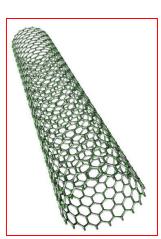




Quantum Dots



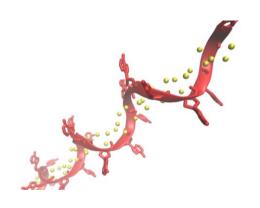
Nanowires



CNTs

- Exploiting their properties is challenging!
 - Not amenable to organization on surfaces in interconnected circuits, networks or arrays
- Self-assembled DNA nanostructures can be used as scaffolds to organize small functional nanocomponents

DNA Origami



- Large enough for conventional lithographic techniques
- DNA is a charged molecule => hydrophilic surfaces

- The DNA origami are 2D structures obtained by folding a long genomic ss-DNA by means of hybridization with many short staples (synthetic ss-DNA); 165 × 165 nm
- Use "sticky ends" to attach functionalized nanostructures (CNTs, nanoparticles, etc.)

